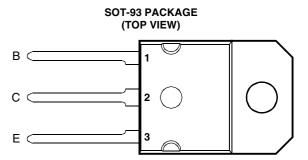
BOURNS®

- Designed for Complementary Use with the BD250 Series
- 125 W at 25°C Case Temperature
- 25 A Continuous Collector Current
- 40 A Peak Collector Current
- Customer-Specified Selections Available



Pin 2 is in electrical contact with the mounting base.

MDTRAAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
	BD249		55		
Collector-emitter voltage ($R_{BE} = 100 \Omega$)	BD249A	N.	70	V	
	BD249B	VCER	90	v	
	BD249C		115		
	BD249	V _{CEO}	45		
Collector-emitter voltage (I _C = 30 mA)	BD249A		60	V	
	BD249B		80		
	BD249C		100		
Emitter-base voltage		V _{EBO}	5	V	
Continuous collector current		I _C	25	Α	
Peak collector current (see Note 1)		I _{CM}	40	Α	
Continuous base current	I _B	5	Α		
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)	P_{tot}	125	W		
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3	3)	P_{tot}	3	W	
Unclamped inductive load energy (see Note 4)		½Ll _C ²	90	mJ	
Operating junction temperature range		T _j	-65 to +150	°C	
Storage temperature range		T _{stg}	-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds		T_L	250	°C	

NOTES: 1. This value applies for $t_p \le 0.3$ ms, duty cycle $\le 10\%$.

- 2. Derate linearly to 150° C case temperature at the rate of 1 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 24 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 0.4 A, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = 20 V.



electrical characteristics at 25°C case temperature

	PARAMETER		TEST CONDITIO	NS	MIN	TYP	MAX	UNIT	
W	Collector-emitter			BD249 BD249A	45 60			٧	
V _{(BR)CEO}	breakdown voltage	CEO breakdown voltage	breakdown voltage $I_C = 30 \text{ mA}$ $I_B = 0$ (see Note 5)	I _B = 0	BD249B	80			V
		,		BD249C	100				
		V _{CE} = 55 V	$V_{BE} = 0$	BD249			0.7		
lana	Collector-emitter	$V_{CE} = 70 V$	$V_{BE} = 0$	BD249A			0.7	mA	
ICES	cut-off current	$V_{CE} = 90 V$	$V_{BE} = 0$	BD249B			0.7		
		V _{CE} = 115 V	$V_{BE} = 0$	BD249C			0.7		
1	Collector cut-off	V _{CE} = 30 V	I _B = 0	BD249/249A			1	mA	
I _{CEO}	current	$V_{CE} = 60 V$	$I_B = 0$	BD249B/249C			1	ША	
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0				1	mA	
	Forward current	$V_{CE} = 4 V$	I _C = 1.5 A		25				
h _{FE}	transfer ratio	$V_{CE} = 4 V$	$I_C = 15 A$	(see Notes 5 and 6)	10				
		$V_{CE} = 4 V$	$I_C = 25 A$		5				
V _{CE(sat)}	Collector-emitter	I _B = 1.5 A	I _C = 15 A	(see Notes 5 and 6)	4		1.8	V	
* CE(sat)	saturation voltage	$I_B = 5 A$	$I_C = 25 A$				4	•	
V _{BE}	Base-emitter	$V_{CE} = 4 V$	I _C = 15 A	(see Notes 5 and 6)	and 6)		2	٧	
▼BE	voltage	$V_{CE} = 4 V$	$I_C = 25 A$	(See Notes 5 and 6)			4	•	
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 1 A	f = 1 kHz	25		_		
h _{fe}	Small signal forward current transfer ratio	V _{CE} = 10 V	I _C = 1 A	f = 1 MHz	3				

NOTES: 5. These parameters must be measured using pulse techniques, $t_p = 300$ µs, duty cycle $\leq 2\%$.

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
R _{BJC} Junction to case the mal resistance			1	°C/W
R _{eJA} Junction to free air thermal resistance			42	°C/W

resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t _{on}	Turn-on time	I _C = 5 A	$I_{B(on)} = 0.5 A$	$I_{B(off)} = -0.5 A$		0.3		μs
t _{off}	Turn-off time	$V_{BF(off)} = -5 V$	$R_1 = 5 \Omega$	$t_{\rm p} = 20 \ \mu s, \ dc \le 2\%$		0.9		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

^{6.} These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN VS COLLECTOR CURRENT 1000 V_{CE} = 4 V T_C = 25°C t_p = 300 μs, duty cycle < 2% 100 100 100 100 100

1.0 10 I_c - Collector Current - A

Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE

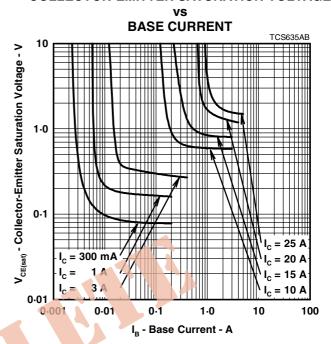
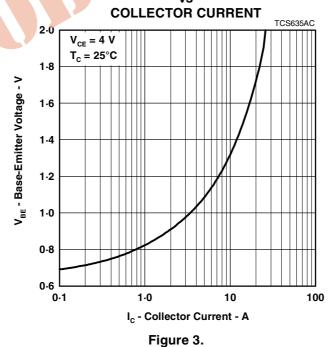


Figure 2.

BASE-EMITTER VOLTAGE



PRODUCT INFORMATION

MAXIMUM SAFE OPERATING REGIONS

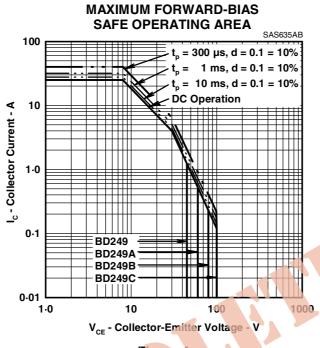


Figure 4.

THERMAL INFORMATION

MAXIMUM POWER DISSIPATION VS CASE TEMPERATURE TIS635AA TIS635AA

Figure 5.